

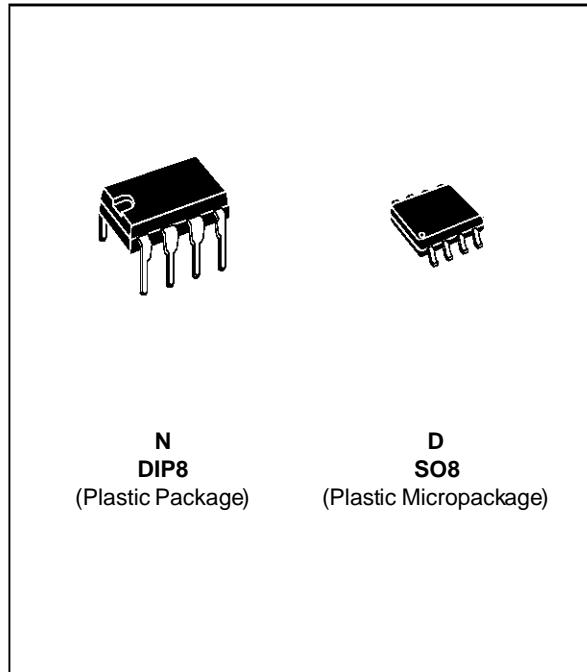
LOW POWER DUAL VOLTAGE COMPARATORS

- WIDE SINGLE SUPPLY VOLTAGE RANGE OR DUAL SUPPLIES +2V TO +36V OR $\pm 1V$ TO $\pm 18V$
- VERY LOW SUPPLY CURRENT (0.4mA) INDEPENDENT OF SUPPLY VOLTAGE (1 mW/comparator at +5V)
- LOW INPUT BIAS CURRENT : 25nA TYP
- LOW INPUT OFFSET CURRENT : $\pm 5nA$ TYP
- INPUT COMMON-MODE VOLTAGE RANGE INCLUDES GROUND
- LOW OUTPUT SATURATION VOLTAGE : 250mV TYP. ($I_O = 4mA$)
- DIFFERENTIAL INPUT VOLTAGE RANGE EQUAL TO THE SUPPLY VOLTAGE
- TTL, DTL, ECL, MOS, CMOS COMPATIBLE OUTPUTS

DESCRIPTION

This device consists of two independent low power voltage comparators designed specifically to operate from a single supply over a wide range of voltages. Operation from split power supplies is also possible.

These comparators also have a unique characteristic in the fact that the input common-mode voltage range includes ground even though operated from a single power supply voltage.

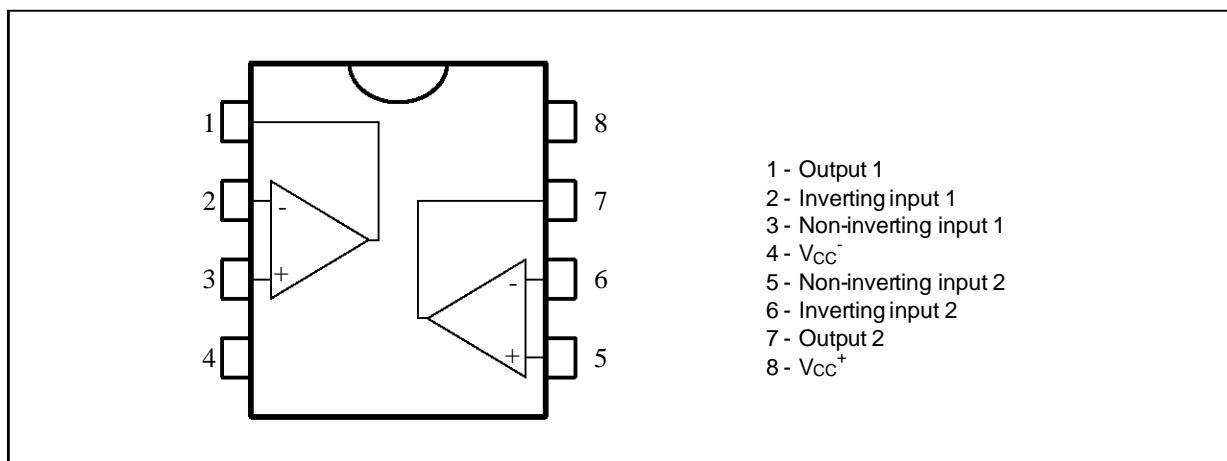


ORDER CODES

Part Number	Temperature Range	Package	
		N	D
LM2903	-40, +125°C	•	•
Example : LM2903N			

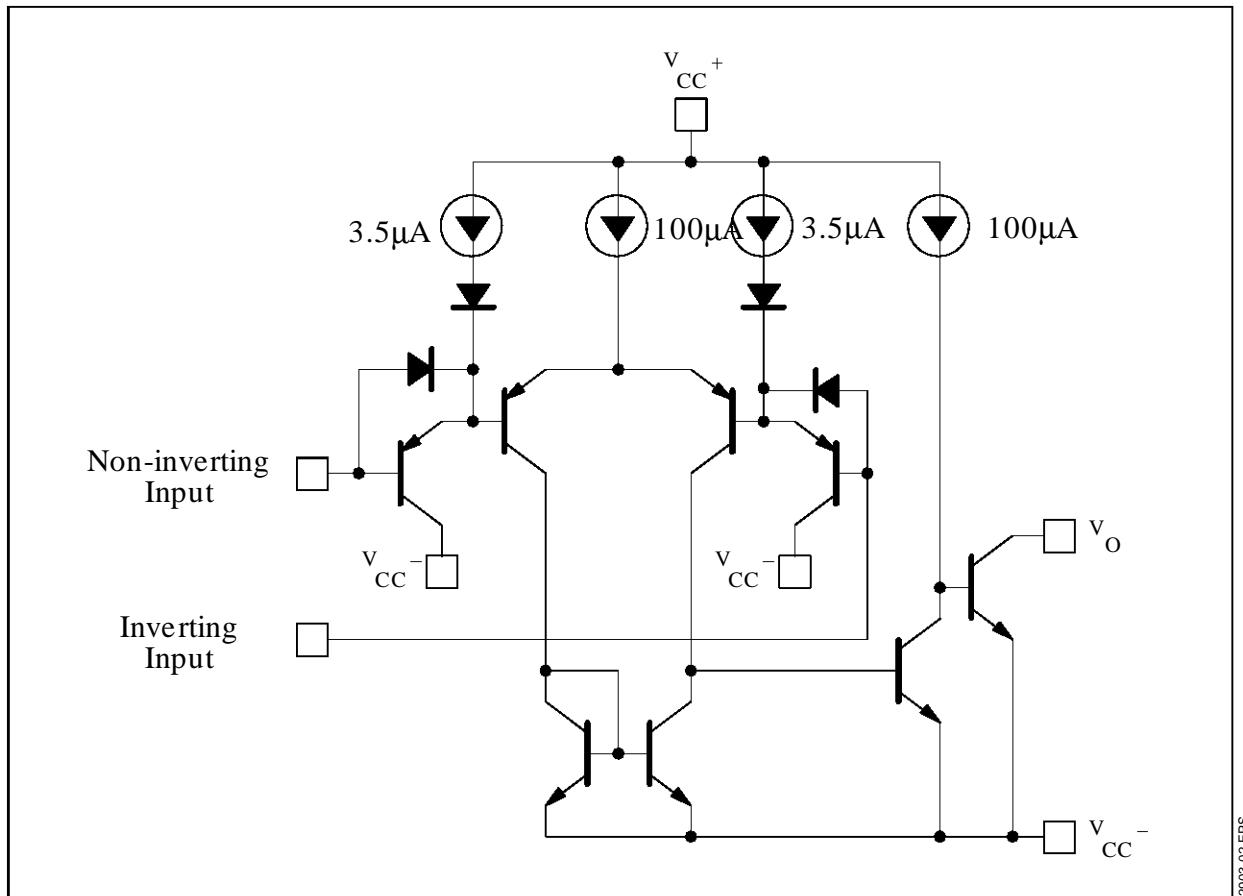
2903-01.TBL

PIN CONNECTIONS (top view)



LM2903

SCHEMATIC DIAGRAM (1/2 LM2903)



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	± 18 or 36	V
V_{id}	Differential Input Voltage	± 36	V
V_i	Input Voltage	-0.3 to +36	V
	Output Short-circuit to Ground – (note 1)	Infinite	
P_{tot}	Power Dissipation	830	mW
T_{oper}	Operating Free-air Temperature Range	-40 to +125	°C
T_{stg}	Storage Temperature Range	-65 to +150	°C

Notes : 1. Short-circuit from the output to V_{CC}^+ can cause excessive heating and eventual destruction. The maximum output current is approximately 20mA, independent of the magnitude of V_{CC}^+ .

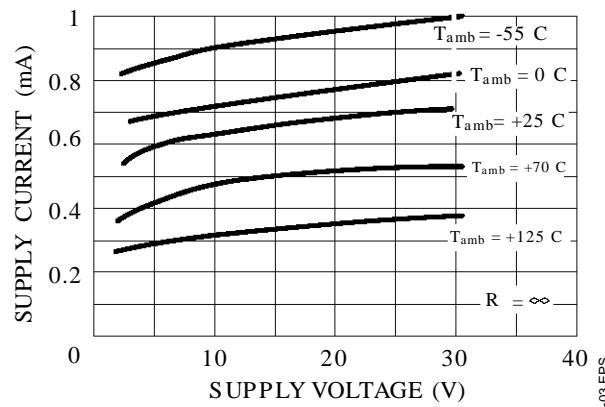
ELECTRICAL CHARACTERISTICS $V_{CC^+} = +5V, V_{CC^-} = 0V, T_{amb} = 25^\circ C$ (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Unit
V_{io}	Input Offset Voltage – (note 2) $T_{amb} = +25^\circ C$ $T_{min.} \leq T_{amb} \leq T_{max.}$		1	7 15	mV
I_{ib}	Input Bias Current – (note 3) $T_{amb} = +25^\circ C$ $T_{min.} \leq T_{amb} \leq T_{max.}$		25	250 400	nA
I_{io}	Input Offset Current $T_{amb} = +25^\circ C$ $T_{min.} \leq T_{amb} \leq T_{max.}$		5	50 150	nA
A_{vd}	Large Signal Voltage Gain $V_{CC} = 15V, R_L = 15k\Omega, V_o = 1$ to $11V$	25	200		V/mV
I_{cc}	Supply Current (all comparators) $V_{CC} = 5V$, no load $V_{CC} = 30V$, no load		0.4 1	1 2.5	mA
V_{icm}	Input Common Mode Voltage Range - (note 4) $T_{amb} = +25^\circ C$ $T_{min.} \leq T_{amb} \leq T_{max.}$	0 0		$V_{CC^+} - 1.5$ $V_{CC^+} - 2$	V
V_{id}	Differential Input Voltage - (note 6)			V_{CC^+}	V
I_{sink}	Output Sink Current ($V_{id} = -1V, V_O = 1.5V$)	6	16		mA
V_{OL}	Low Level Output Voltage ($V_{id} = -1V, I_{sink} = 4mA$) $T_{amb} = 25^\circ C$ $T_{min.} \leq T_{amb} \leq T_{max}$		250	400 700	mV
I_{OH}	High Level Output Current ($V_{id} = 1V, V_{CC} = V_O = 30V$) $T_{amb} = 25^\circ C$ $T_{min.} \leq T_{amb} \leq T_{max}$		0.1	1	nA μA
t_{re}	Response Time ($R_L = 5.1k\Omega$ to V_{CC^+}) – (note 5)		1.3		μs
t_{rel}	Large Signal Response Time ($V_i = TTL, V_{ref} = +1.4 V, R_L = 5.1k\Omega$ to V_{CC^+})		300		ns

2903-03.TBL

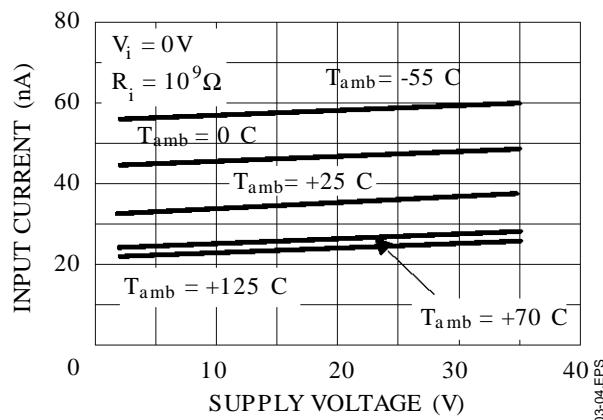
- Notes :**
2. At output switch point, $V_O \approx 1.4V$, $R_S = 0\Omega$ with V_{CC^+} from 5V to 30V and over the full input common-mode range (0V to $V_{CC^+} 1.5V$).
 3. The direction of the input current is out of the IC due to the PNP input stage. This current is essentially constant, independent of the state of the output, so no loading charge exists on the reference or input lines.
 4. The input common-mode voltage of either input signal voltage should not be allowed to go negative by more than 0.3V.
The upper end of the common-mode voltage range is $V_{CC^+} - 1.5V$, but either or both inputs can go to +30V without damage.
 5. The response time specified is for a 100mV input step with 5mV overdrive. For larger overdrive signals 300ns can be obtained.
 6. As long as the other voltage remains within the common-mode range the comparator will provide a proper output state. The low input voltage state must not be less than -0.3V (or 0.3V below the negative power supply, if used).

SUPPLY CURRENT versus
SUPPLY VOLTAGE



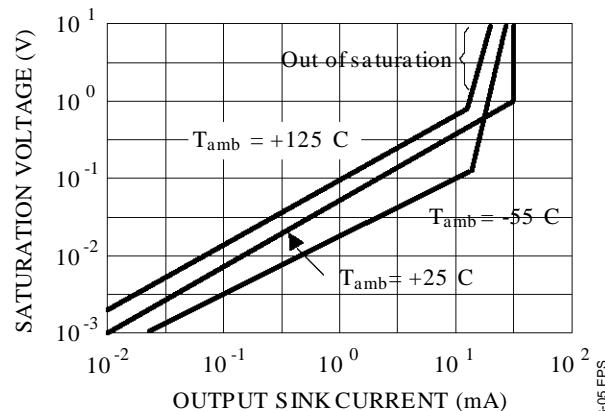
2903-03.EPS

INPUT CURRENT versus
SUPPLY VOLTAGE



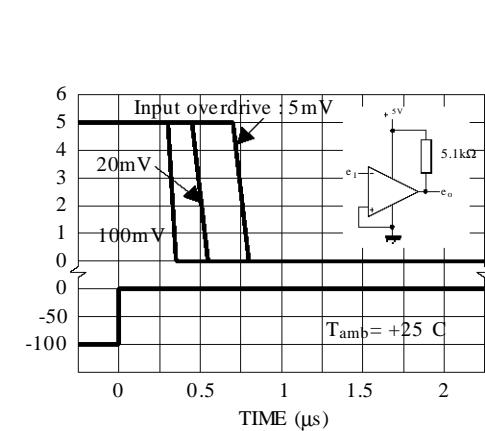
2903-04.EPS

OUTPUT SATURATION VOLTAGE
versus OUTPUT CURRENT



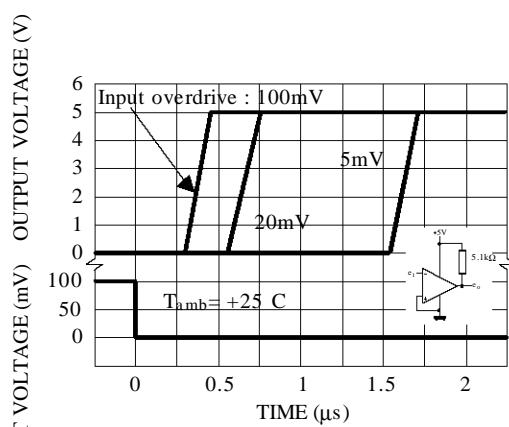
2903-05.EPS

RESPONSE TIME FOR VARIOUS INPUT
OVERDRIVES - NEGATIVE TRANSITION



2903-06.EPS

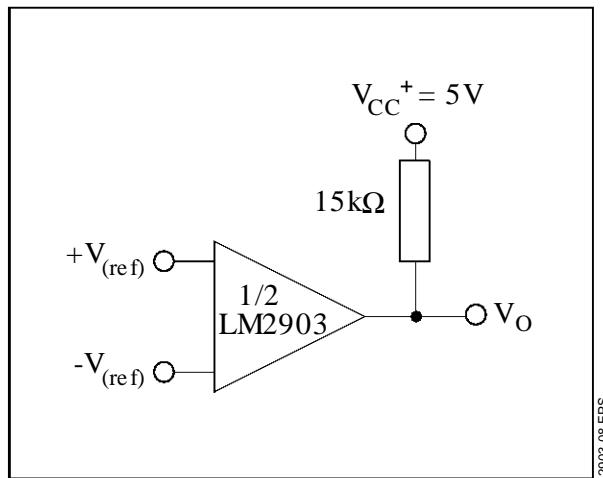
RESPONSE TIME FOR VARIOUS INPUT
OVERDRIVES - POSITIVE TRANSITION



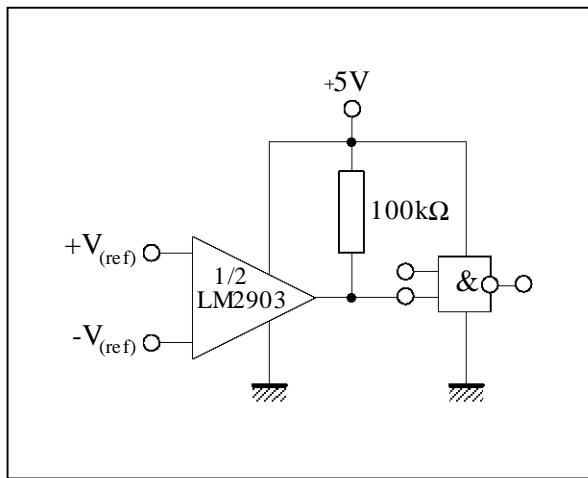
2903-07.EPS

TYPICAL APPLICATIONS

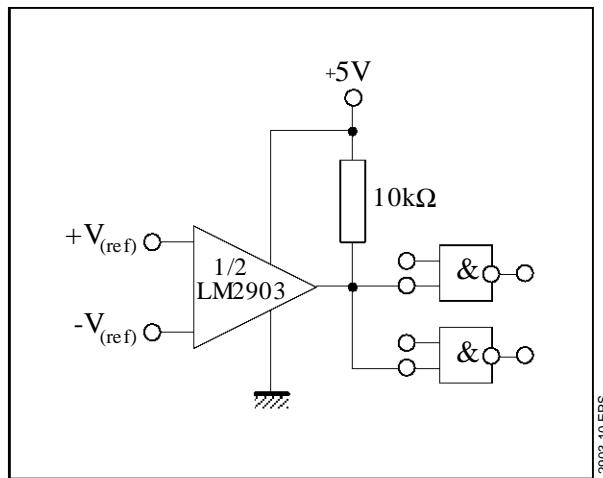
BASIC COMPARATOR



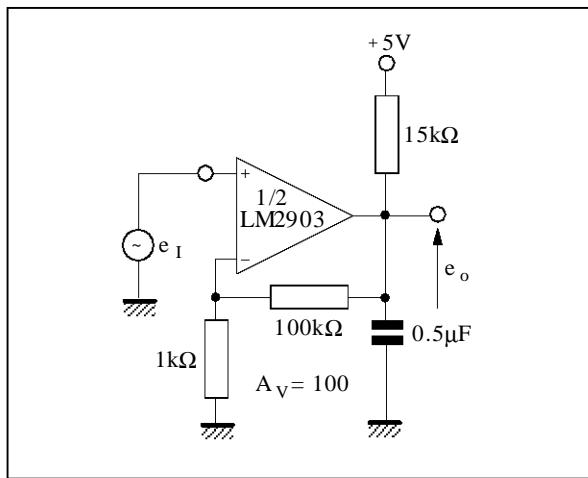
DRIVING CMOS



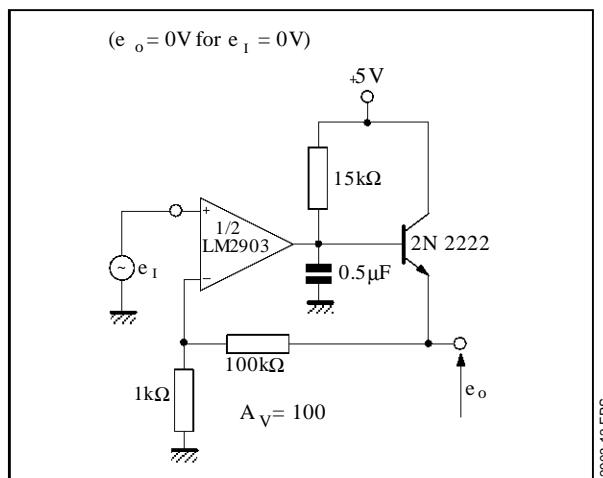
DRIVING TTL



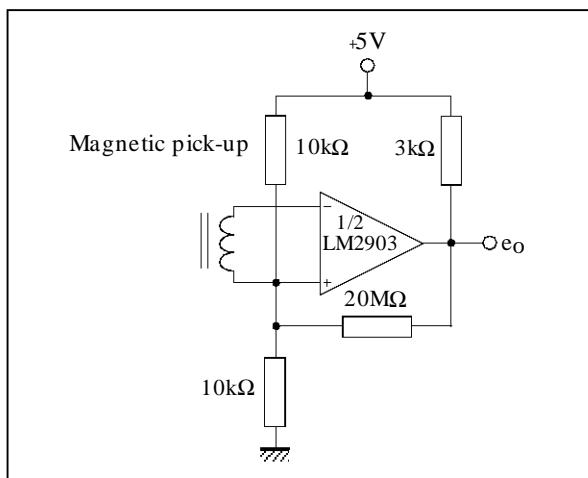
LOW FREQUENCY OP AMP



LOW FREQUENCY OP AMP

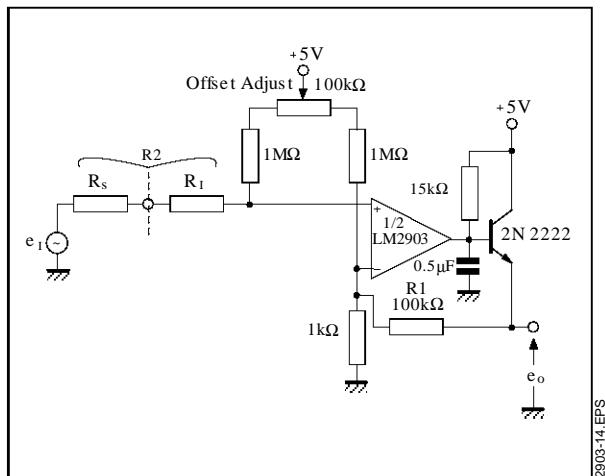


TRANSDUCER AMPLIFIER

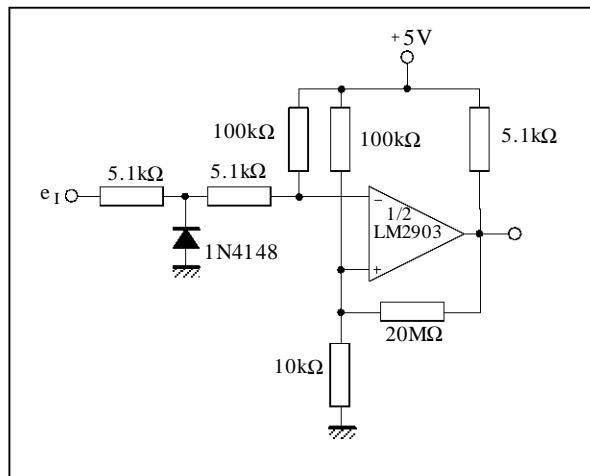


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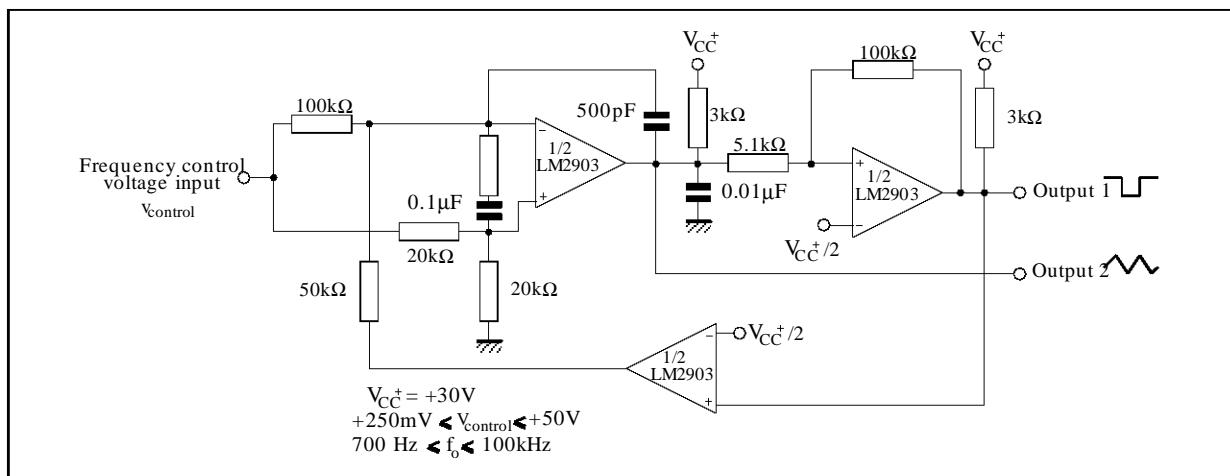
LOW FREQUENCY OP AMP WITH OFFSET ADJUST



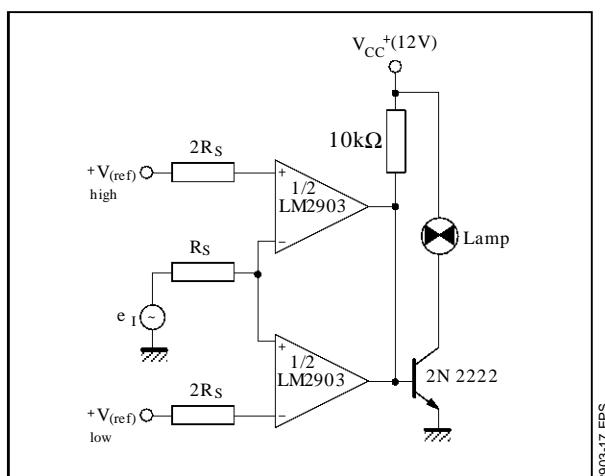
ZERO CROSSING DETECTOR (SINGLE POWER SUPPLY)



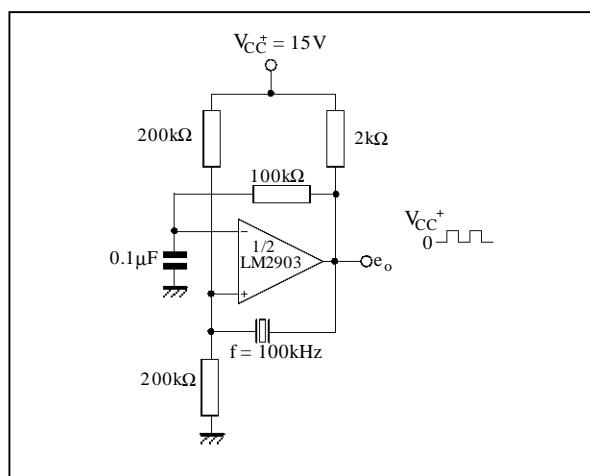
TWO DECADES HIGH FREQUENCY VCO



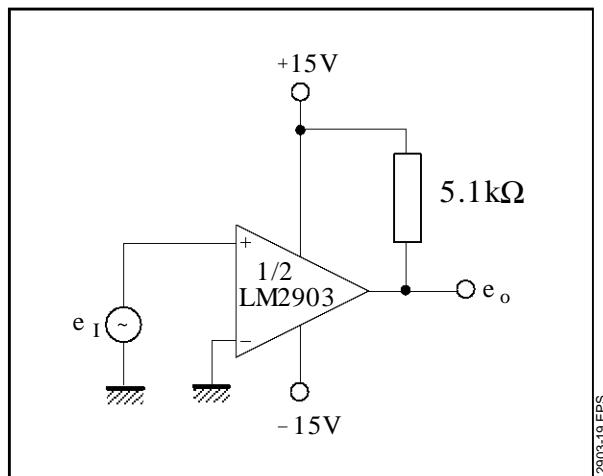
LIMIT COMPARATOR



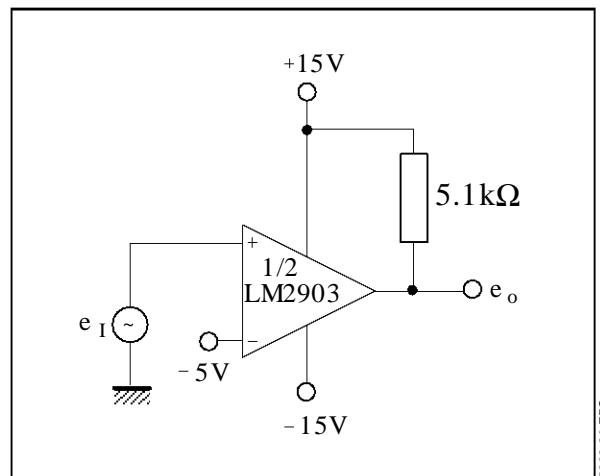
CRYSTAL CONTROLLED OSCILLATOR



SPLIT-SUPPLY APPLICATIONS
ZERO CROSSING DETECTOR



COMPARATOR WITH A NEGATIVE
REFERENCE

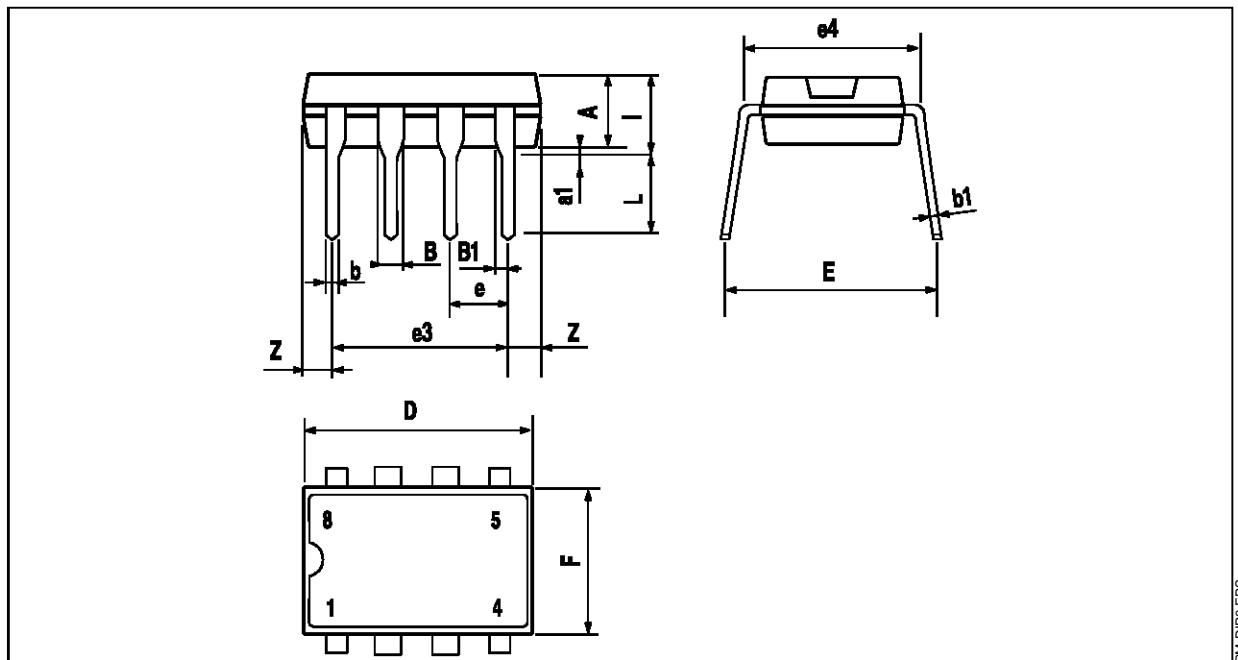


2903-19.EPS

2903-20.EPS

LM2903

PACKAGE MECHANICAL DATA 8 PINS -PLASTIC DIP OR CERDIP

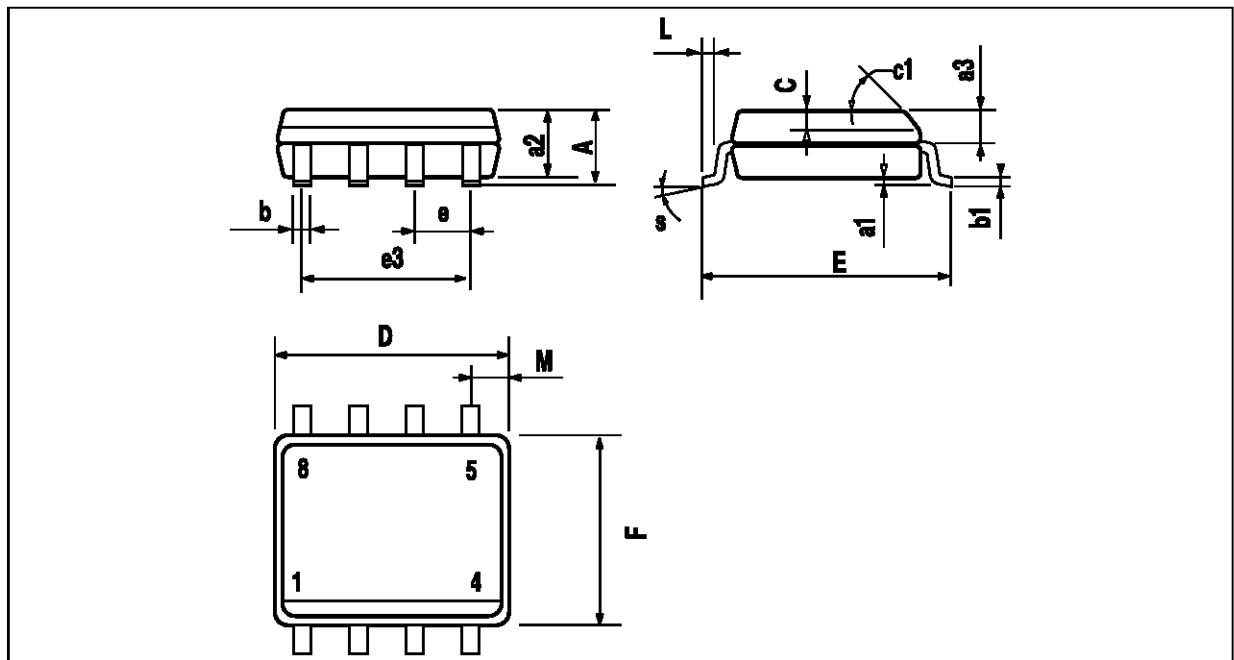


PMI-DIP8.EPS

Dimensions	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A		3.32			0.131	
a1	0.51			0.020		
B	1.15		1.65	0.045		0.065
b	0.356		0.55	0.014		0.022
b1	0.204		0.304	0.008		0.012
D		10.92			0.430	
E	7.95		9.75	0.313		0.384
e		2.54			0.100	
e3		7.62			0.300	
e4		7.62			0.300	
F			6.6			0.260
i			5.08			0.200
L	3.18		3.81	0.125		0.150
Z			1.52			0.060

DIP8.TBL

PACKAGE MECHANICAL DATA
8 PINS -PLASTIC MICROPACKAGE (SO)



PM-SO8.EPS

Dimensions	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.75			0.069
a1	0.1		0.25	0.004		0.010
a2			1.65			0.065
a3	0.65		0.85	0.026		0.033
b	0.35		0.48	0.014		0.019
b1	0.19		0.25	0.007		0.010
C	0.25		0.5	0.010		0.020
c1		45° (typ.)				
D	4.8		5.0	0.189		0.197
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		3.81			0.150	
F	3.8		4.0	0.150		0.157
L	0.4		1.27	0.016		0.050
M			0.6			0.024
S		8° (max.)				

SO8.TBL

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